

RCD075N19

Nch 190V 7.5A Power MOSFET

V_{DSS}	190V
R _{DS(on)} (Max.)	336m Ω
I _D	7.5A
P_D	52W

Features

- 1) Low voltage drive (4V drive).
- 2) Low on-resistance.
- 3) Fast switching speed.
- 4) Drive circuits can be simple.
- 5) Parallel use is easy.
- 6) Pb-free lead plating; RoHS compliant
- 7) 100% Avalanche tested

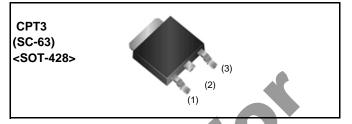
Application

Switching Power Supply

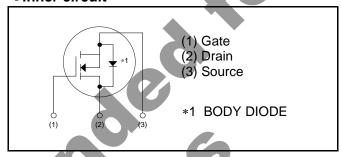
Automotive Motor Drive

Automotive Solenoid Drive

Outline



•Inner circuit



Packaging specifications

	Packaging	Taping
	Reel size (mm)	330
Type	Tape width (mm)	16
Type	Basic ordering unit (pcs)	2,500
	Taping code	TL
	Marking	C07N19

● Absolute maximum ratings(T_a = 25°C)

Parameter	10	Symbol	Value	Unit
Drain - Source voltage		V_{DSS}	190	V
Continuous drain current	T _c = 25°C	I _D *1	±7.5	А
Continuous diain current	T _c = 100°C	I _D *1	±4.1	А
Pulsed drain current	I _{D,pulse} *2	±30	А	
Gate - Source voltage		V_{GSS}	±20	V
Avalanche energy, single pulse	Avalanche energy, single pulse		4.81	mJ
Avalanche current		I _{AR} *3	3.8	А
Power dissipation	T _c = 25°C	P_{D}	52	W
rowei dissipation	$T_a = 25^{\circ}C^{*4}$	P_{D}	0.85	W
Junction temperature		T _j	150	°C
Range of storage temperature		T _{stg}	-55 to +150	°C

●Thermal resistance

Parameter	Symbol	Values			Unit
raiametei	Symbol	Min.	Тур.	Max.	Offic
Thermal resistance, junction - case	R_{thJC}	-	-	2.36	°C/W
Thermal resistance, junction - ambient *4	R_{thJA}	-	-	147	°C/W
Soldering temperature, wavesoldering for 10s	T_{sold}	1	-	265	°C

●Electrical characteristics(T_a = 25°C)

Dorometer	Cumbal	Conditions	(Values		Lloit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Drain - Source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V$, $I_D = 1mA$	190	ı	-	V
Zero gate voltage drain current	laca	$V_{DS} = 190V, V_{GS} = 0V$ $T_j = 25^{\circ}C$	-	33	10	^
Zero gate voltage drain current	I _{DSS}	$V_{DS} = 190V, V_{GS} = 0V$ $T_j = 125^{\circ}C$		ı	100	μΑ
Gate - Source leakage current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	•	±100	nA
Gate threshold voltage	V _{GS (th)}	$V_{DS} = 10V$, $I_D = 1mA$	0.5	ı	2.5	V
		$V_{GS} = 10V, I_D = 3.8A$	-	240	336	
Static drain - source	*5	$V_{GS} = 4.0V, I_D = 3.8A$	-	248	347	m O
on - state resistance	R _{DS(on)} *5	$V_{GS} = 10V, I_D = 3.8A$ $T_j = 125^{\circ}C$	-	360	505	mΩ
Forward transfer admittance	9 _{fs}	$V_{DS} = 10V, I_D = 3.8A$	4	8	-	S



●Electrical characteristics(T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit
r ai ai ii etei	Symbol	Conditions	Min.	Тур.	Max.	Offic
Input capacitance	C _{iss}	$V_{GS} = 0V$	-	1100	-	
Output capacitance	C _{oss}	V _{DS} = 25V	-	60	-	pF
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	35		
Turn - on delay time	t _{d(on)} *5	$V_{DD} \simeq 100 V$, $V_{GS} = 10 V$	-	12		
Rise time	t _r *5	I _D = 3.8A	-	14	-	no
Turn - off delay time	t _{d(off)} *5	$R_L = 26.7\Omega$	-	80	-	ns
Fall time	t _f *5	$R_G = 10\Omega$		45	-	

•Gate Charge characteristics($T_a = 25$ °C)

Parameter	Symbol	Conditions	Values			Unit
r ai ai ii e lei	Symbol	Conditions	Min.	Тур.	Max.	Offic
Total gate charge	Q_g^{*5}	V _{DD} ≃ 100V	C	30	-	
Gate - Source charge	Q _{gs} *5	$I_D = 7.5A$	·	3.0	-	nC
Gate - Drain charge	Q _{gd} *5	V _{GS} = 10V	-	6.5	-	
Gate plateau voltage	V _(plateau)	$V_{DD} \approx 100V, I_D = 7.5A$	-	2.5	-	V

●Body diode electrical characteristics (Source-Drain)(T_a = 25°C)

Parameter	Symbol Conditions		Values			Unit
Parameter	Symbol	Conditions		Тур.	Max.	Offic
Continuous source current	l _s *1	T _c = 25°C	-	ı	7.5	Α
Pulsed source current	I _{SM} *2	1 c = 25 C	-	1	30	Α
Forward voltage	V _{SD} *5	$V_{GS} = 0V, I_{S} = 7.5A$	-	-	1.5	V
Reverse recovery time	t _{rr} *5	I _S = 3.8A	-	70	-	ns
Reverse recovery charge	Q _{rr} *5	di/dt = 100A/μs	-	180	-	nC

^{*1} Limited only by maximum temperature allowed.

^{*2} Pw \leq 10 μ s, Duty cycle \leq 1%

^{*3} L $^{\simeq}$ 500 μ H, V_{DD} = 50V, Rg = 25 Ω , starting T $_{j}$ = 25°C

^{*4} Mounted on a epoxy PCB FR4 (20mm × 30mm × 0.8mm)

^{*5} Pulsed

•Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

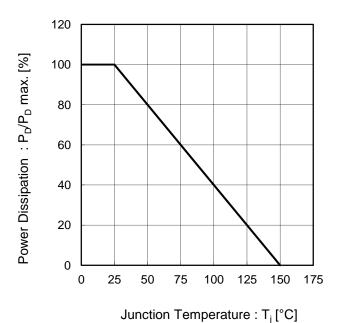
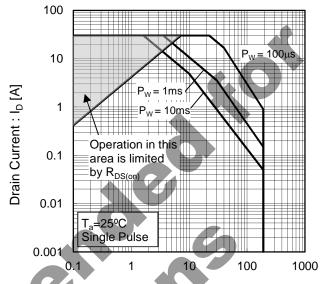
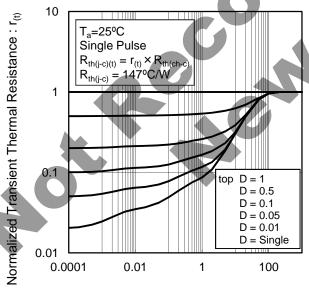


Fig.2 Maximum Safe Operating Area



Drain - Source Voltage : V_{DS} [V]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width



Pulse Width : $P_W[s]$

• Electrical characteristic curves

Fig.4 Avalanche Current vs Inductive Load

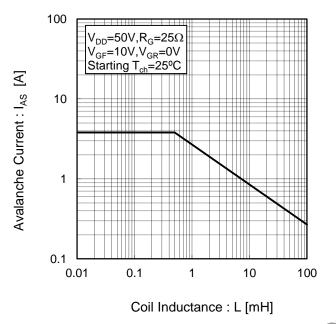
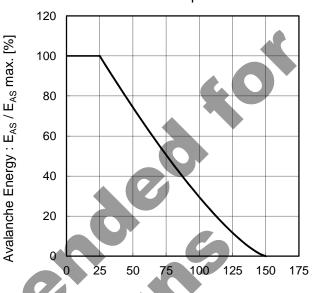
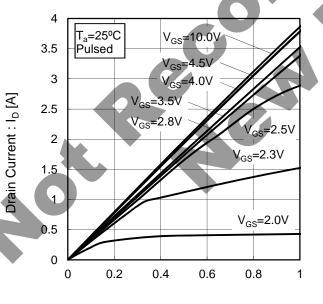


Fig.5 Avalanche Energy Derating Curve vs Junction Temperature



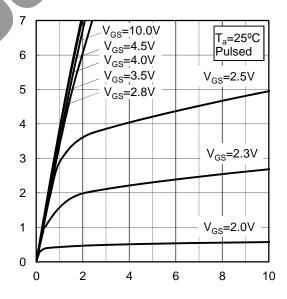
Junction Temperature : T_i [°C]

Fig.6 Typical Output Characteristics(I)



Drain - Source Voltage : V_{DS} [V]

Fig.7 Typical Output Characteristics(II)



Drain - Source Voltage : V_{DS} [V]

Drain Current : I_D [A]

5

• Electrical characteristic curves

Fig.8 Breakdown Voltage vs. Junction Temperature 250 Normarize Drain - Source Breakdown Voltage $V_{GS} = 0V$ 240 $I_D = 1mA$ 230 220 210 $: V_{(BR)DSS}[V]$ 200 190 180 170 160 150 -50 0 50 100 150 Junction Temperature : T_i [°C]

T_a= 125°C
T_a= 75°C
T_a= 25°C
T_a= -25°C

Gate - Source Voltage : V_{GS} [V]

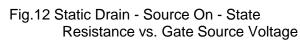
Fig.11 Transconductance vs. Drain Current

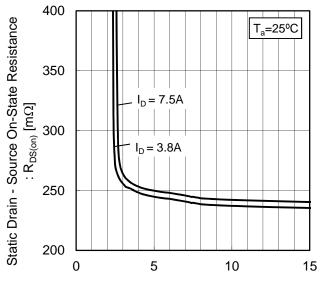
Fig.10 Gate Threshold Voltage vs. Junction Temperature 3.0 $V_{DS} = 10V$ $I_D = 1 mA$ Gate Threshold Voltage: V_{GS(th)} [V] 2.5 2.0 1.5 1.0 0.5 0.0 -50 -25 75 100 125 150 0 25 50 Junction Temperature : T_i [°C]

Drain Current: I_D [A]

0.001

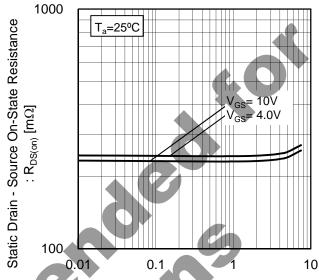
• Electrical characteristic curves





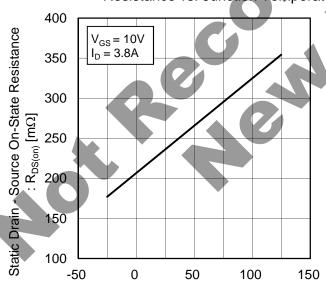
Gate - Source Voltage : V_{GS} [V]

Fig.13 Static Drain - Source On - State Resistance vs. Drain Current(I)



Drain Current : I_D [A]

Fig.14 Static Drain - Source On - State
Resistance vs. Junction Temperature



Junction Temperature : T_j [°C]

•Electrical characteristic curves

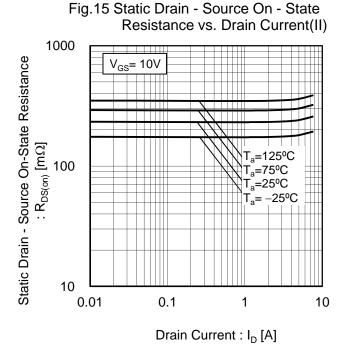
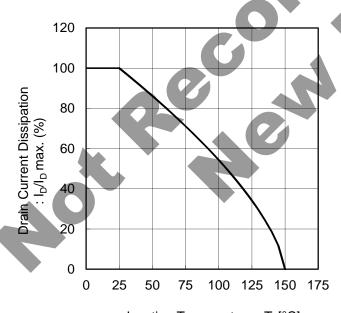


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current(III)

1000 $V_{GS} = 4.0V$ $V_{GS} =$

Fig.17 Drain Current Derating Curve



Junction Temperature : T_i [°C]

• Electrical characteristic curves

Fig.18 Typical Capacitance

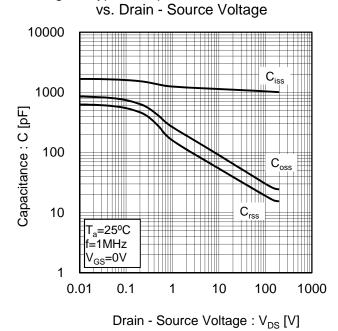
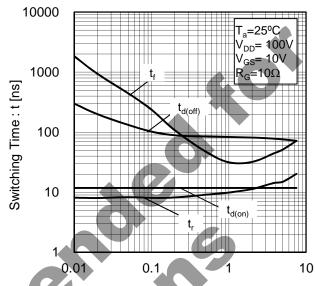


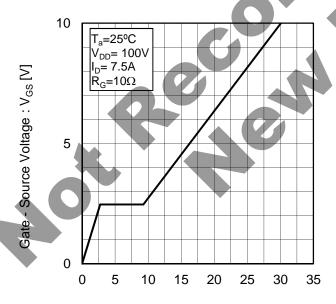
Fig.19 Switching Characteristics



Drain Current : I_D [A]

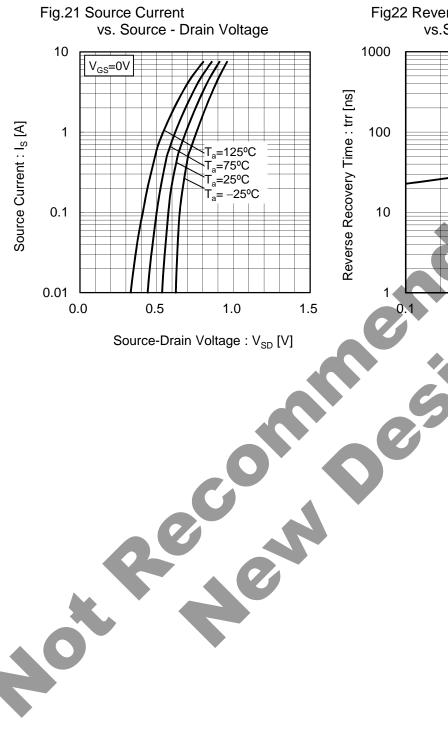
Prairi Codros Voltago : VDS [V]

Fig.20 Dynamic Input Characteristics



Total Gate Charge : Q_g [nC]

•Electrical characteristic curves



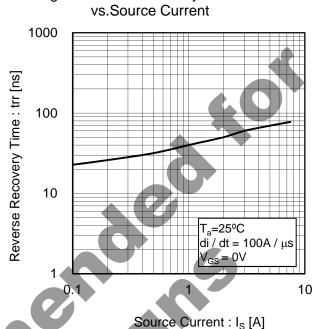


Fig22 Reverse Recovery Time



●Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

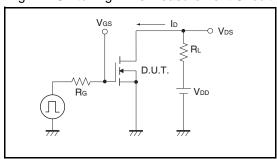


Fig.2-1 Gate Charge Measurement Circuit

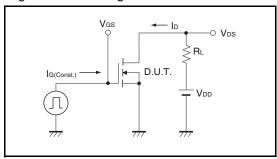


Fig.3-1 Avalanche Measurement Circuit

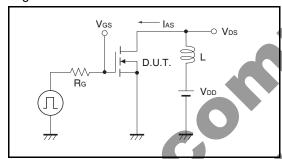


Fig.1-2 Switching Waveforms

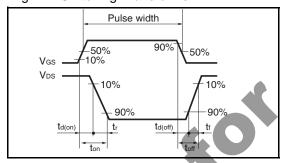


Fig.2-2 Gate Charge Waveform

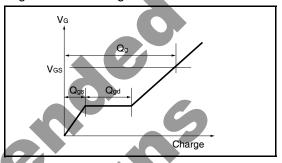
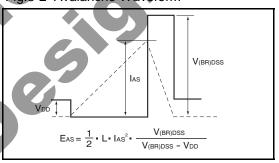
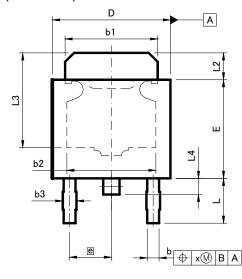


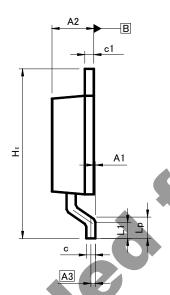
Fig.3-2 Avalanche Waveform

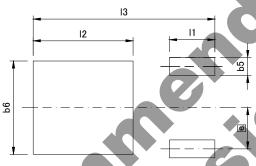


●Dimensions (Unit : mm)









DIM	MILIM	ETERS	INCHES		
DIW	MIN	MAX	MIN	MAX	
A1	0.00	0.15	0	0.006	
A2	2.20	2.50	0.087	0.098	
A3	0.:	25	0.0	01	
b	0.55	0.75	0.022	0.03	
b1	5.00	5.30	0.197	0.209	
b2	5.0	00	0.3	20	
b3	0.	75	0.0	03	
С	0.40	0.60	0.016	0.024	
c1	0.40	0.60	0.016	0.024	
D	6.30	6.70	0.248	0.264	
E	5.40	5.80	0.213	0.228	
e	2.3	30	0.09		
HE	9.00	10.00	0.354	0.394	
L	2.20	2.80	0.087	0.11	
L1	0.80	1.40	0.031	0.055	
L2	1.20	1.80	0.047	0.071	
L3	5.3	30	0.209		
L4	0.9	90	0.035		
Lp	1.00	1.60	0.039	0.063	
х	_	0.25	_	0.01	

DIM	MILIM	LIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX	
b5	_	1.00	ı	0.04	
b6	_	5.20	-	0.205	
11	-	2.50	ı	0.098	
12	_	5.50	-	0.217	
13	_	10.00	_	0.394	

Dimension in mm/inches

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 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power, exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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